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Product Qualification Report

- 1. Purpose: The purpose of this specification is to document the Qualification Report for TP65H150G4PS
- 2. Scope
 - a. The products listed in section 1 are fully qualified and released to production.
 - b. Qualification test results on these products may reference existing qualification results of similar products per the use of generic data as defined in section 2.2 of AEC-Q101 Rev D1. Such referencing is justified by the structural similarity of the products. At least one lot per qualification test in section 7 has been performed on TP65H150G4PS
- 3. Qualification Process
 - a. All Fab Lots were processed separately with a discrete amount of time between lots. All lots were assembled using the same Assembly House, on the same assembly line. All lots undergo Final Test using the documented test flow and are screened against documented test limits as appropriate to their part number. All processes and test conditions are documented and maintained under revision control as part of the Transphorm Quality Management System.
 - b. Documented process and test conditions that are used for qualification of products are designated "Process of Record". Changes to the Process of Record are managed through the Process/Product Change Notification Procedure, which is part of the Transphorm Quality Management System.
 - c. Lot and sample sizes reference the minimum number required.
- 4. ESD Results: 3 parts pass for each test
 - a. Standard Used: ANSI/ESDA/JEDEC JS-002-2018

Product Family	CDM	HBM
TP65H150G4PS	\geq 2000V / C7	$\pm 450V / 1A$

- 5. Reliability Testing
 - a. Failed devices are analyzed for root cause and correction. Only a representative sample needs to be analyzed, though some level of analysis will be applied to every failed part. Acceptable root cause and corrective action and successful demonstration of corrective and preventative actions will constitute successful qualification of a device. The part and/or qualification family can be qualified as long as containment of any problems is demonstrated until corrective and/or preventative actions are in place.

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- 6. Electrical Test Parameters
 - a. Components submitted for qualification testing must meet all datasheet parameters before and after stress testing

Parameter	Symbol	Conditions	LSL	USL	Unit
Drain to source leakage	IDSS	V _{DS} = 650V		25	μA
current		$V_{GS} = 0V$			
		TJ=25⁰C			
Gate to Source Forward	lgss	V _{GS} =20V		100	nA
Leakage Current					
Drain source on resistance	R _{DS}	V _{GS} = 10V		180	mΩ
		ID=8.5A			
		TJ= 25⁰C			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS}	3.3	4.8	V
		ID=0.5mA			

7. Electrical Reliability Qualification Test Results

TEST	SYMBOL	CONDITIONS	MIN	RESULT
			SAMPLE	
High Temperature	HTRB	T _J =150°C	3 lots	0 Fails
Reverse Bias		$V_{DS} = 520V$	77 parts per lot	PASS
		1000 HRS	231 total parts	
Highly	HAST	130°C,85% RH	3 lots	0 Fails
Accelerated Temp		33.3 PSI	77 parts per lot	PASS
and Humidity Test		Bias = 100V	231 total parts	
		96 HRS		
Temperature Cycle	TC	-55°C / 150°C	3 lots	0 Fails
		2 Cycles / HR	77 parts per lot	PASS
		1000 Cycles	231 total parts	
Power Cycle	PC	25°C / 125°C	3 lots	0 Fails
		$\Delta T = 100^{\circ}C$	77 parts per lot	PASS
		7500 Cycles	231 total parts	
High Temperature	HTGB	150°C	3 lots	0 Fails
Gate bias		1000 HRS	77 parts per lot	PASS
		V _{GSS} =20V	231 total parts	

Parts for Power Cycle will be mounted to printed circuit board

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- 8. Referenced Documents
 - a. AEC-Q101: Stress Test Qualification for Automotive Grade Discrete Semiconductors
 - b. JESD47: Stress-Test Driven Qualification of Integrated Circuits
 - c. MIL-PRF-38535: Performance specification-Integrated Circuits Manufacturing General Specification for Department of Defense
 - d. JESD22-A108C: High Temperature Reverse Bias (HTRB)
 - e. JESD22-A110D: Highly Accelerated Temperature and Humidity Stress Test (HAST)
 - f. JESD22-A104D: Temperature Cycle (TC)
 - g. JESD22-A122: Power Cycle (PC)
 - h. JS-001-2012: Electrostatic Discharge Human Body Model
 - i. J-STD-020D.1: Moisture/Reflow Sensitivity Classification
 - j. JESD22-A102: Pre-conditioning
 - k. M2011: Wirebond strength
 - 1. JESD22-B116: Bond Shear
- 9. Signature Approval

Ronald Ban

Ronald Barr VP Quality March 7, 2022